High-temperature 40 V, 1 A Schottky barrier rectifier

28 November 2012

Product data sheet

1. Product profile

1.1 General description

Planar Maximum Efficiency General Application (MEGA) Schottky barrier rectifier with an integrated guard ring for stress protection, encapsulated in a SOD123W small and flat lead Surface-Mounted Device (SMD) plastic package.

1.2 Features and benefits

- Average forward current: $I_{F(AV)} \le 1 A$
- Reverse voltage: $V_R \le 40 V$
- Low forward voltage
- High power capability due to clip-bonding technology
- Small and flat lead SMD plastic package
- AEC-Q101 qualified
- High temperature T_i ≤ 175 °C

1.3 Applications

Quick reference data

- Low voltage rectification
- High efficiency DC-to-DC conversion
- Switch mode power supply
- Reverse polarity protection

1.4 Quick reference data

Symbol	Parameter	Conditions		Min	Тур	Max	Unit
l _F	forward current	T _{sp} = 165 °C		-	-	1.4	А
I _{F(AV)}	average forward current	δ = 0.5 ; f = 20 kHz; T _{amb} ≤ 140 °C; square wave	[1]	-	-	1	A
		δ = 0.5 ; f = 20 kHz; T _{sp} ≤ 170 °C; square wave		-	-	1	A
V _R	reverse voltage	T _j = 25 °C		-	-	40	V
V _F	forward voltage	I _F = 1 A; T _j = 25 °C		-	430	490	mV
I _R	reverse current	$T_j = 25 \text{ °C}; V_R = 40 \text{V}; t_p \leq 300 \mu\text{s}; \\ \delta \leq 0.02 \text{ ; pulsed}$		-	10	50	μA



Table 1.



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Symbol	Parameter	Conditions	Min	Тур	Мах	Unit
t _{rr}	reverse recovery time	$I_R = 0.5 \text{ A}; I_F = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$ $T_j = 25 ^{\circ}\text{C}$	-	4.4	-	ns

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

Pinning information 2.

Table 2.	Pinning	information		
Pin	Symbol	Description	Simplified outline	Graphic symbol
1	К	cathode[1]	1 2	1 🖧 2
2	A	anode	SOD123W	sym001

[1] The marking bar indicates the cathode.

Ordering information 3.

Table 3. Ordering information							
Type number Package							
	Name	Description	Version				
PMEG4010ETR	SOD123W	plastic surface mounted package; 2 leads	SOD123W				

Marking 4.

Table 4. Marking codes	
Type number	Marking code
PMEG4010ETR	EJ

Limiting values 5.

Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions		Min	Max	Unit
V _R	reverse voltage	T _j = 25 °C		-	40	V
I _F	forward current	T _{sp} = 165 °C		-	1.4	А
I _{F(AV)}	average forward current	δ = 0.5 ; f = 20 kHz; T _{amb} ≤ 140 °C; square wave	[1]	-	1	A
		δ = 0.5 ; f = 20 kHz; T_{sp} \leq 170 °C; square wave		-	1	A
I _{FSM}	non-repetitive peak forward current	t_p = 8 ms; $T_{j(init)}$ = 25 °C; square wave		-	50	A
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Symbol	Parameter	Conditions		Min	Max	Unit
P _{tot}	total power dissipation	T _{amb} ≤ 25 °C	[2]	-	680	mW
			[3]	-	1150	mW
			[1]	-	2140	mW
Tj	junction temperature			-	175	°C
T _{amb}	ambient temperature			-55	175	°C
T _{stg}	storage temperature			-65	175	°C

[1] Device mounted on a ceramic Printed-Circuit Board (PCB), Al₂O₃, standard footprint.

[2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.

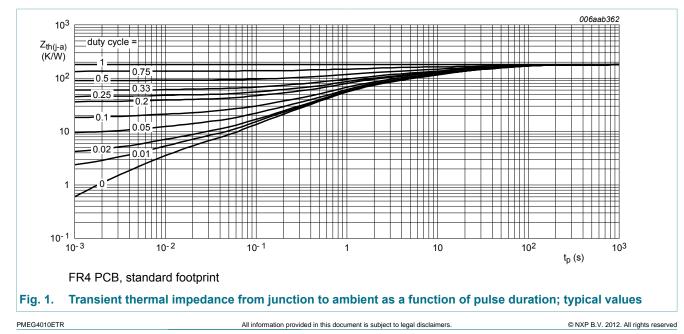
[3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².

6. Thermal characteristics

Table 6. T	hermal characteristics						
Symbol	Parameter	Conditions		Min	Тур	Max	Unit
R _{th(j-a)} thermal resistance from junction to			[1][2]	-	-	220	K/W
	from junction to ambient		[1][3]	-	-	130	K/W
	ampient		[1][4]	-	-	70	K/W
R _{th(j-sp)}	thermal resistance from junction to solder point		[5]	-	-	18	K/W

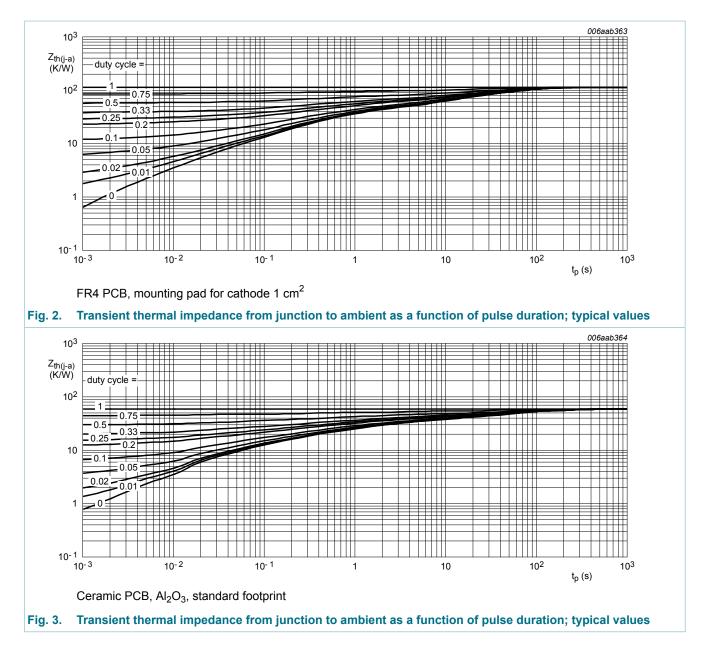
[1] For Schottky barrier diodes thermal runaway has to be considered, as in some applications the reverse power losses P_R are a significant part of the total power losses.

- [2] Device mounted on an FR4 PCB, single-sided copper, tin-plated and standard footprint.
- [3] Device mounted on an FR4 PCB, single-sided copper, tin-plated, mounting pad for cathode 1 cm².
- [4] Device mounted on a ceramic PCB, Al₂O₃, standard footprint.
- [5] Soldering point of cathode tab.



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7. Characteristics

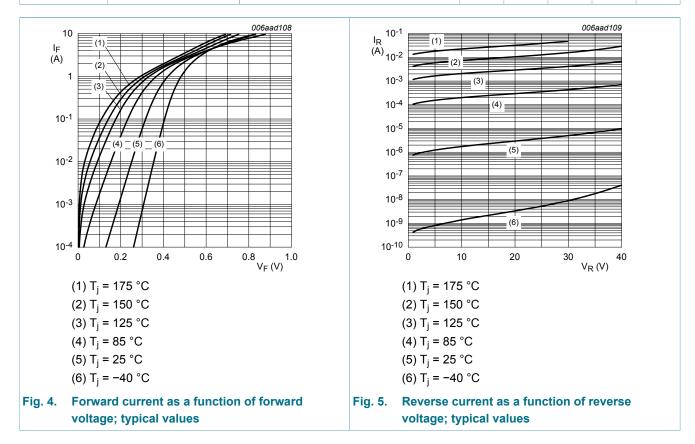
Table 7. Characteristics								
Symbol	Parameter	Conditions		Min	Тур	Max	Unit	
V _F	forward voltage	I _F = 0.1 A; T _j = 25 °C		-	310	360	mV	
		I _F = 1 A; T _j = 25 °C		-	430	490	mV	
		I _F = 1 A; T _j = -40 °C		-	480	570	mV	
		I _F = 1 A; T _j = 125 °C		-	330	410	mV	
		I _F = 1 A; T _j = 150 °C		-	310	390	mV	
		I _F = 1 A; T _j = 175 °C		-	290	370	mV	
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Product data sheet

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Symbol	Parameter	Conditions	Min	Тур	Max	Unit
I _R reverse current		V_R = 10 V; t _p ≤ 300 μs; δ ≤ 0.02 ; T _j = 25 °C; pulsed	-	3	13	μA
		V_R = 40 V; $t_p \le$ 300 µs; $\delta \le$ 0.02 ; T _j = 25 °C; pulsed	-	10	50	μA
		V_R = 40 V; t _p ≤ 300 μs; δ ≤ 0.02 ; T _j = -40 °C; pulsed	-	0.05	1	μA
		$\label{eq:VR} \begin{split} V_{\text{R}} &= 40 \text{ V}; \ t_{\text{p}} \leq 300 \ \text{\mus}; \ \delta \leq 0.02 \ ; \\ T_{\text{j}} &= 125 \ ^{\circ}\text{C}; \ \text{pulsed} \end{split}$	-	6.5	30	mA
C _d	diode capacitance	V _R = 1 V; f = 1 MHz; T _j = 25 °C	-	130	-	pF
		V _R = 10 V; f = 1 MHz; T _j = 25 °C	-	50	-	pF
t _{rr}	reverse recovery time	$I_{F} = 0.5 \text{ A}; I_{R} = 0.5 \text{ A}; I_{R(meas)} = 0.1 \text{ A};$ $T_{j} = 25 \text{ °C}$	-	4.4	-	ns
V _{FRM}	peak forward recovery voltage	I _F = 1 A; dI _F /dt = 40 A/μs; T _j = 25 °C	-	484	-	mV

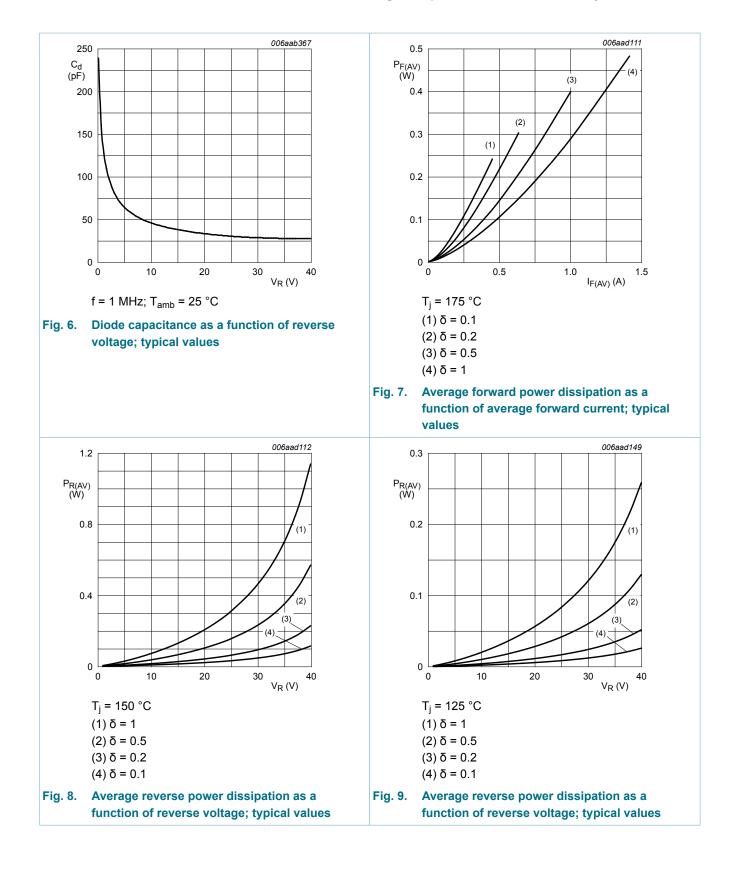


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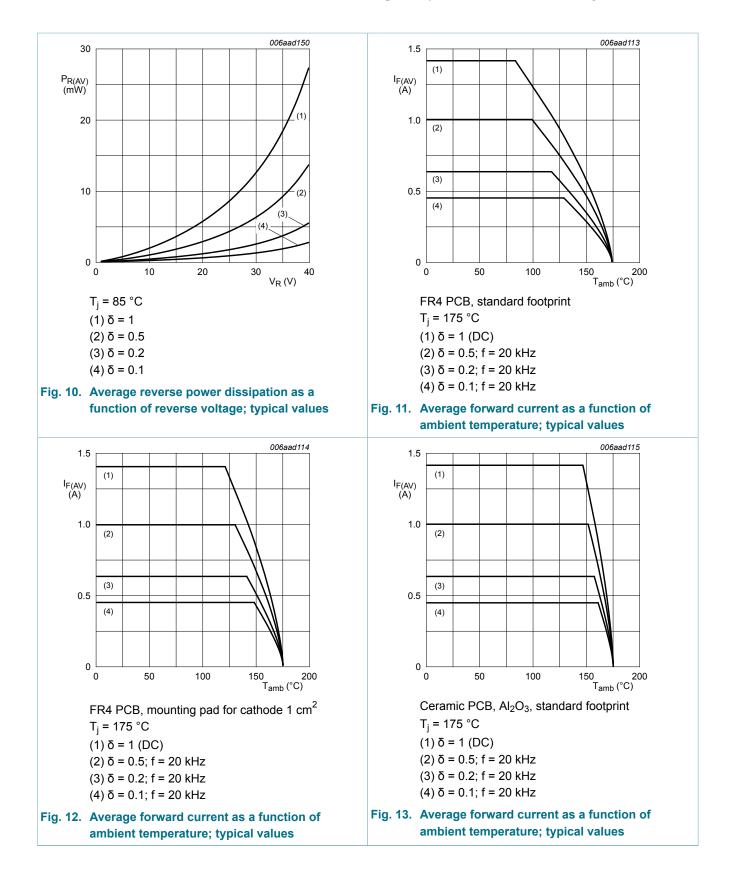
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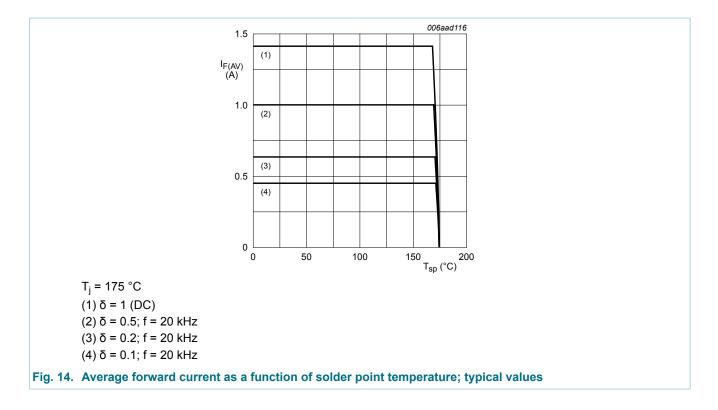


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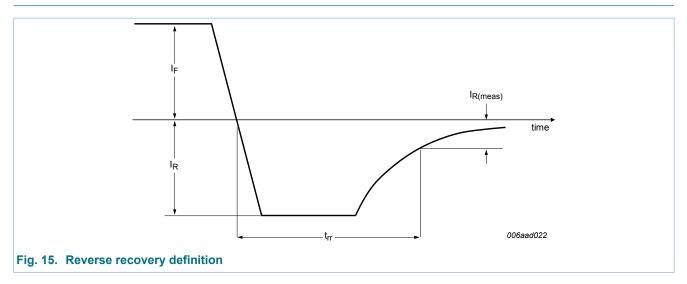
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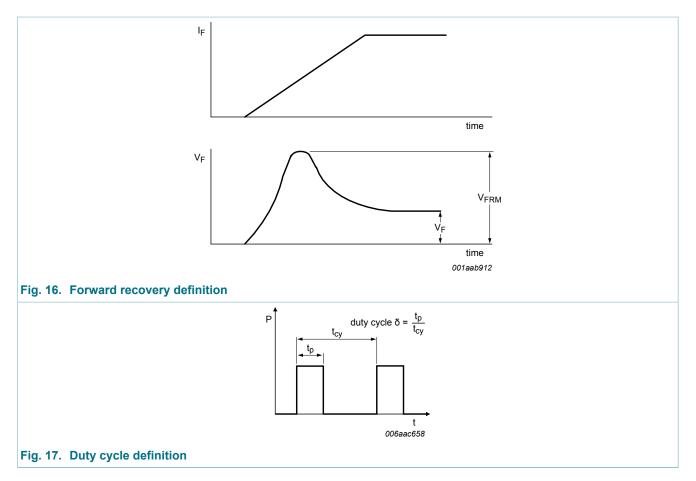


8. Test information



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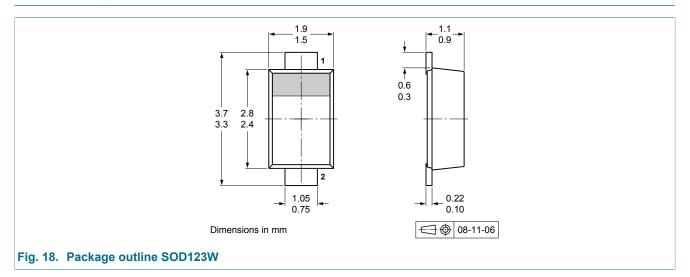
The current ratings for the typical waveforms are calculated according to the equations: $I_{F(AV)} = I_M \times \delta$ with I_M defined as peak current, $I_{RMS} = I_{F(AV)}$ at DC, and $I_{RMS} = I_M \times \sqrt{\delta}$ with I_{RMS} defined as RMS current.

8.1 Quality information

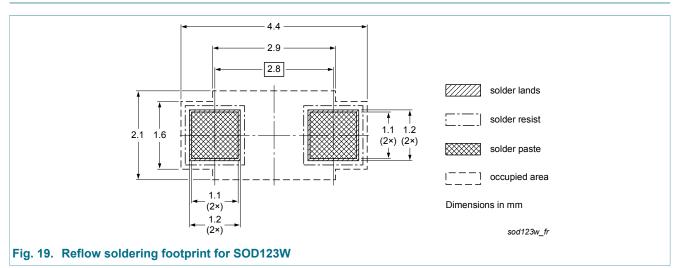
This product has been qualified in accordance with the Automotive Electronics Council (AEC) standard Q101 - Stress test qualification for discrete semiconductors, and is suitable for use in automotive applications.

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9. Package outline



10. Soldering



11. Revision history

Table 8. Revision history						
Data sheet ID	Release date	Data sheet status	Change notice	Supersedes		
PMEG4010ETR v.2	20121128	Product data sheet	-	PMEG4010ETR v.1		
Modifications:	Table 7. Characteri	stics: I _R value corrected	·	,		
PMEG4010ETR v.1	20120926	Product data sheet	-	-		

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12. Legal information

12.1 Data sheet status

Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
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